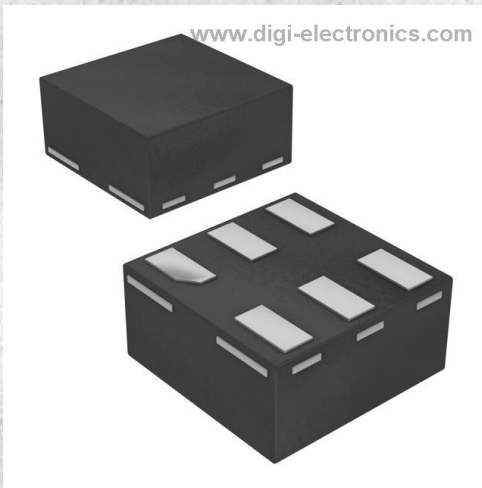


74AUP1G132GS,132 Datasheet



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DiGi Electronics Part Number	74AUP1G132GS,132-DG
Manufacturer	Nexperia USA Inc.
Manufacturer Product Number	74AUP1G132GS,132
Description	IC GATE NAND 1CH 2-INP 6XSON
Detailed Description	NAND Gate IC 1 Channel Schmitt Trigger 6-XSON, SOT1202 (1x1)



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Purchase and inquiry

Manufacturer Product Number:

74AUP1G132GS,132

Series:

74AUP

Logic Type:

NAND Gate

Number of Inputs:

2

Voltage - Supply:

0.8V ~ 3.6V

Current - Output High, Low:

4mA, 4mA

Input Logic Level - High:

0.6V ~ 2.29V

Operating Temperature:

-40°C ~ 125°C

Supplier Device Package:

6-XSON, SOT1202 (1x1)

Base Product Number:

74AUP1G132

Manufacturer:

Nexperia USA Inc.

Product Status:

Active

Number of Circuits:

1

Features:

Schmitt Trigger

Current - Quiescent (Max):

500 nA

Input Logic Level - Low:

0.1V ~ 0.88V

Max Propagation Delay @ V, Max CL:

7.8ns @ 3.3V, 30pF

Mounting Type:

Surface Mount

Package / Case:

6-XFDN

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8542.39.0001

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

74AUP1G132

Low-power 2-input NAND Schmitt trigger

Rev. 10 — 23 September 2024

Product data sheet

1. General description

The 74AUP1G132 is a single 2-input NAND gate with Schmitt-trigger inputs. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low static power consumption; $I_{CC} = 0.9 \mu\text{A}$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low noise overshoot and undershoot $< 10\%$ of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.

4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74AUP1G132GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1
74AUP1G132GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G132GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G132GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202
74AUP1G132GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3
74AUP1G132GZ	-40 °C to +125 °C	XSON5	plastic thermal enhanced extremely thin small outline package with side-wettable flanks (SWF); no leads; 5 terminals; body 1.1 × 0.85 × 0.5 mm	SOT8065-1

5. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1G132GW	aE
74AUP1G132GM	aE
74AUP1G132GN	aE
74AUP1G132GS	aE
74AUP1G132GX	aE
74AUP1G132GZ	aE

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram

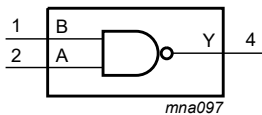


Fig. 1. Logic symbol



Fig. 2. IEC logic symbol

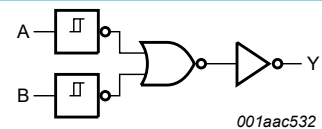
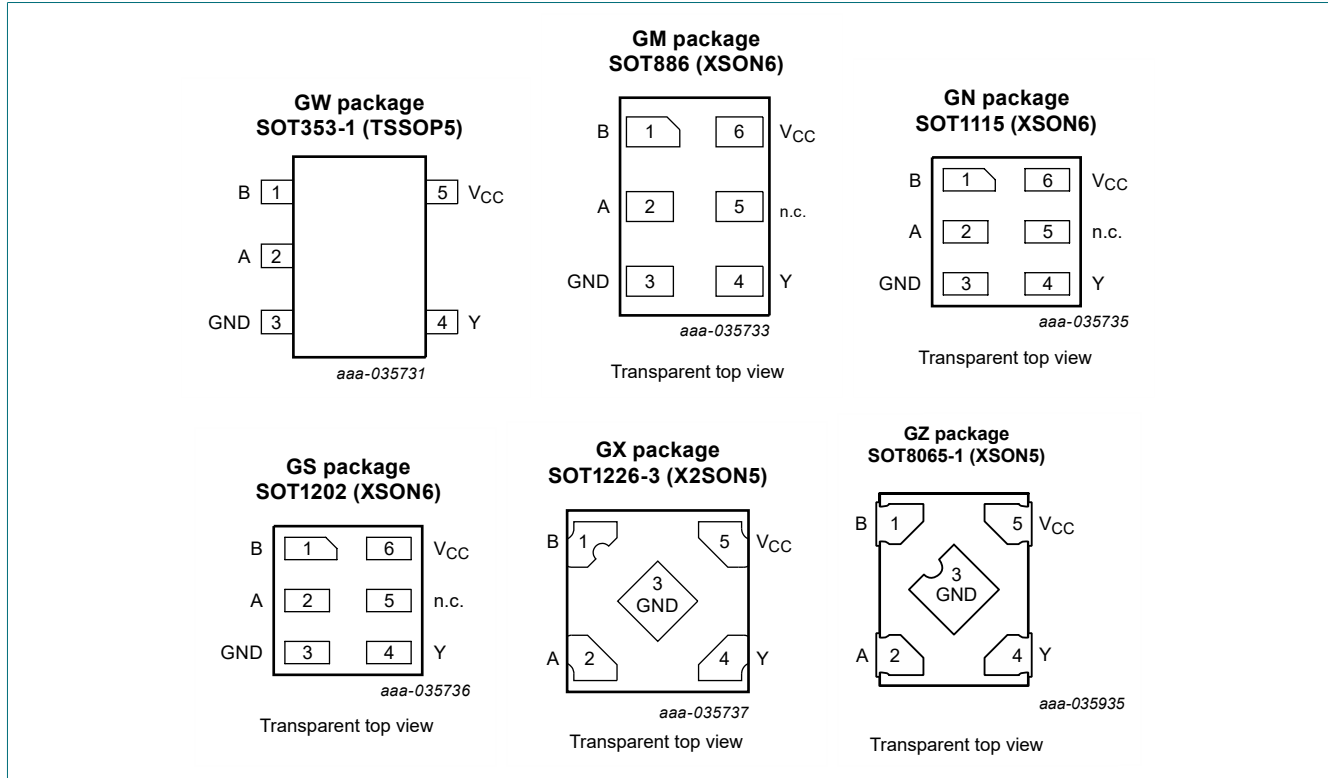


Fig. 3. Logic diagram

7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin		Description
	TSSOP5, XSON5 and X2SON5	XSON6	
B	1	1	data input
A	2	2	data input
GND	3	3	ground (0 V)
Y	4	4	data output
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input		Output
A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
V_I	input voltage		[1] -0.5	+4.6	V
I_{OK}	output clamping current	$V_O < 0$ V	-50	-	mA
V_O	output voltage	Active mode and Power-down mode	[1] -0.5	+4.6	V
I_O	output current	$V_O = 0$ V to V_{CC}	-	±20	mA
I_{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[2] -	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: P_{tot} derates linearly with 3.0 mW/K above 67 °C.

For SOT8065-1 (XSON5) package: P_{tot} derates linearly with 3.2 mW/K above 72 °C.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
V_I	input voltage		0	3.6	V
V_O	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; $V_{CC} = 0$ V	0	3.6	V
T_{amb}	ambient temperature		-40	+125	°C

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V		
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V [1]	-	-	40	μA
C _I	input capacitance	V _I = GND or V _{CC} ; V _{CC} = 0 V to 3.6 V	-	1.1	-	pF
C _O	output capacitance	V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
T_{amb} = -40 °C to +85 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V		

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V [1]	-	-	50	μA
T_{amb} = -40 °C to +125 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V		
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V		
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V [1]	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11.1. Transfer characteristics

Table 8. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
V_{T+}	positive-going threshold voltage	see Fig. 4 and Fig. 5								
		$V_{CC} = 0.8 \text{ V}$	0.30	-	0.60	0.30	0.60	0.30	0.62	V
		$V_{CC} = 1.1 \text{ V}$	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		$V_{CC} = 1.4 \text{ V}$	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		$V_{CC} = 1.65 \text{ V}$	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		$V_{CC} = 2.3 \text{ V}$	1.37	-	1.77	1.37	1.77	1.37	1.80	V
V_{T-}	negative-going threshold voltage	see Fig. 4 and Fig. 5								
		$V_{CC} = 0.8 \text{ V}$	0.10	-	0.60	0.10	0.60	0.10	0.60	V
		$V_{CC} = 1.1 \text{ V}$	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		$V_{CC} = 1.4 \text{ V}$	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		$V_{CC} = 1.65 \text{ V}$	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		$V_{CC} = 2.3 \text{ V}$	0.69	-	1.04	0.69	1.04	0.69	1.04	V
V_H	hysteresis voltage	$(V_{T+} - V_{T-})$; see Fig. 4, Fig. 5, Fig. 6 and Fig. 7								
		$V_{CC} = 0.8 \text{ V}$	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		$V_{CC} = 1.1 \text{ V}$	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		$V_{CC} = 1.4 \text{ V}$	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		$V_{CC} = 1.65 \text{ V}$	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		$V_{CC} = 2.3 \text{ V}$	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		$V_{CC} = 3.0 \text{ V}$	0.79	-	1.31	0.79	1.31	0.79	1.31	V

11.2. Waveforms transfer characteristics

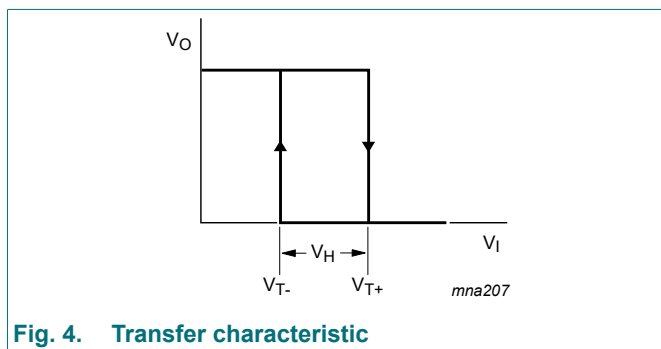


Fig. 4. Transfer characteristic

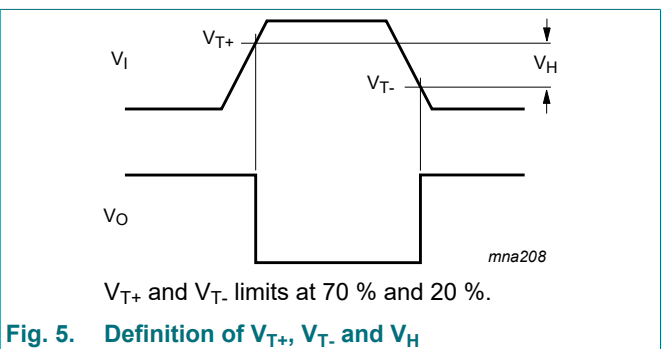
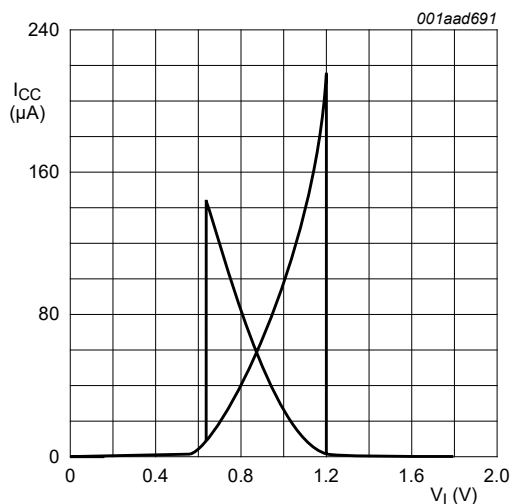
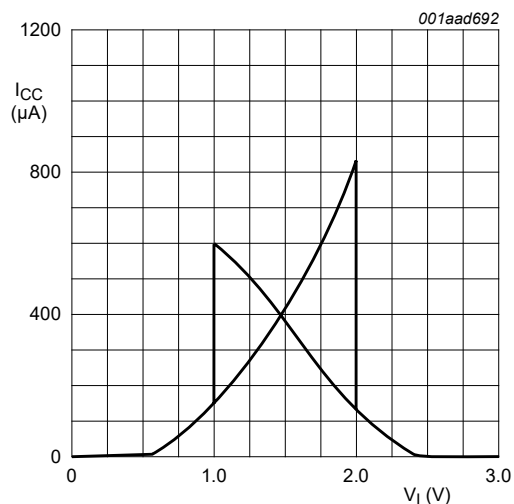


Fig. 5. Definition of V_{T+} , V_{T-} and V_H

Fig. 6. Typical transfer characteristics; $V_{CC} = 1.8 \text{ V}$ Fig. 7. Typical transfer characteristics; $V_{CC} = 3.0 \text{ V}$

12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
$C_L = 5 \text{ pF}$										
t_{pd}	propagation delay	A or B to Y; see Fig. 8 [2]								
		$V_{CC} = 0.8 \text{ V}$	-	22.5	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	2.6	6.3	13.4	2.4	15.1	2.4	16.6	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.2	4.6	8.2	1.9	9.7	1.9	10.7	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	1.9	3.9	6.6	1.7	7.9	1.7	8.7	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	3.2	5.3	1.5	6.2	1.5	6.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.6	2.9	4.7	1.4	5.6	1.4	6.2	ns
$C_L = 10 \text{ pF}$										
t_{pd}	propagation delay	A or B to Y; see Fig. 8 [2]								
		$V_{CC} = 0.8 \text{ V}$	-	26.1	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.0	7.2	15.4	2.7	17.3	2.7	19.0	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.5	5.2	9.3	2.2	11.0	2.2	12.1	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.3	4.5	7.5	2.0	9.0	2.0	9.9	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.1	3.8	6.1	1.8	7.2	1.8	7.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	3.5	5.5	1.8	6.5	1.8	7.2	ns
$C_L = 15 \text{ pF}$										
t_{pd}	propagation delay	A or B to Y; see Fig. 8 [2]								
		$V_{CC} = 0.8 \text{ V}$	-	29.6	-	-	-	-	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$	3.3	8.0	17.2	3.0	19.4	3.0	21.3	ns
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	2.8	5.8	10.4	2.5	12.3	2.5	13.5	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	2.6	5.0	8.3	2.3	10.0	2.3	11.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	2.3	4.2	6.7	2.1	7.9	2.1	8.7	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.2	3.9	6.1	2.0	7.3	2.0	8.0	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C_L = 30 pF										
t _{pd}	propagation delay	A or B to Y; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	39.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	3.8	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	3.2	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	2.9	14.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	2.7	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	2.7	10.1	ns
C_L = 5 pF, 10 pF, 15 pF and 30 pF										
C _{PD}	power dissipation capacitance	f _i = 1 MHz; V _i = GND to V _{CC} [3]								
		V _{CC} = 0.8 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	pF	

[1] All typical values are measured at nominal V_{CC}.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

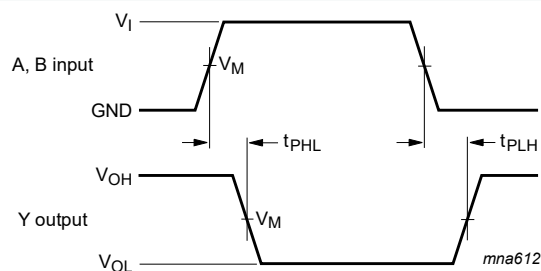
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

12.1. Waveforms and test circuit



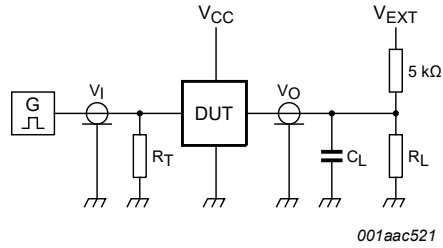
Measurement points are given in Table 10.

V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig. 8. The data input (A or B) to output (Y) propagation delays

Table 10. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	V _I	t _r = t _f
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns



Test data is given in [Table 11](#).

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V_{EXT}		
V_{CC}	C_L	R_L [1]	t_{PLH} , t_{PHL}	t_{PZH} , t_{PHZ}	t_{PZL} , t_{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

- [1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$.
For measuring propagation delays, setup and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

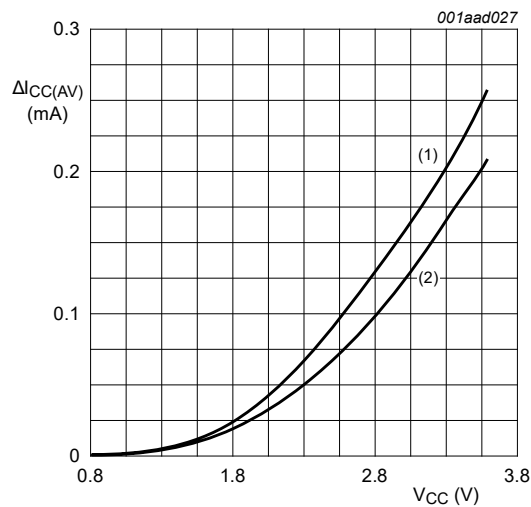
13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

$P_{\text{add}} = f_i \times (t_r \times \Delta I_{\text{CC(AV)}} + t_f \times \Delta I_{\text{CC(AV)}}) \times V_{\text{CC}}$ where:

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $\Delta I_{\text{CC(AV)}}$ = average additional supply current (μA).

Average $\Delta I_{\text{CC(AV)}}$ differs with positive or negative input transitions, as shown in [Fig. 10](#).



(1) Positive-going edge.

(2) Negative-going edge.

Linear change of V_I between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Fig. 10. Average I_{CC} as a function of V_{CC}

14. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1

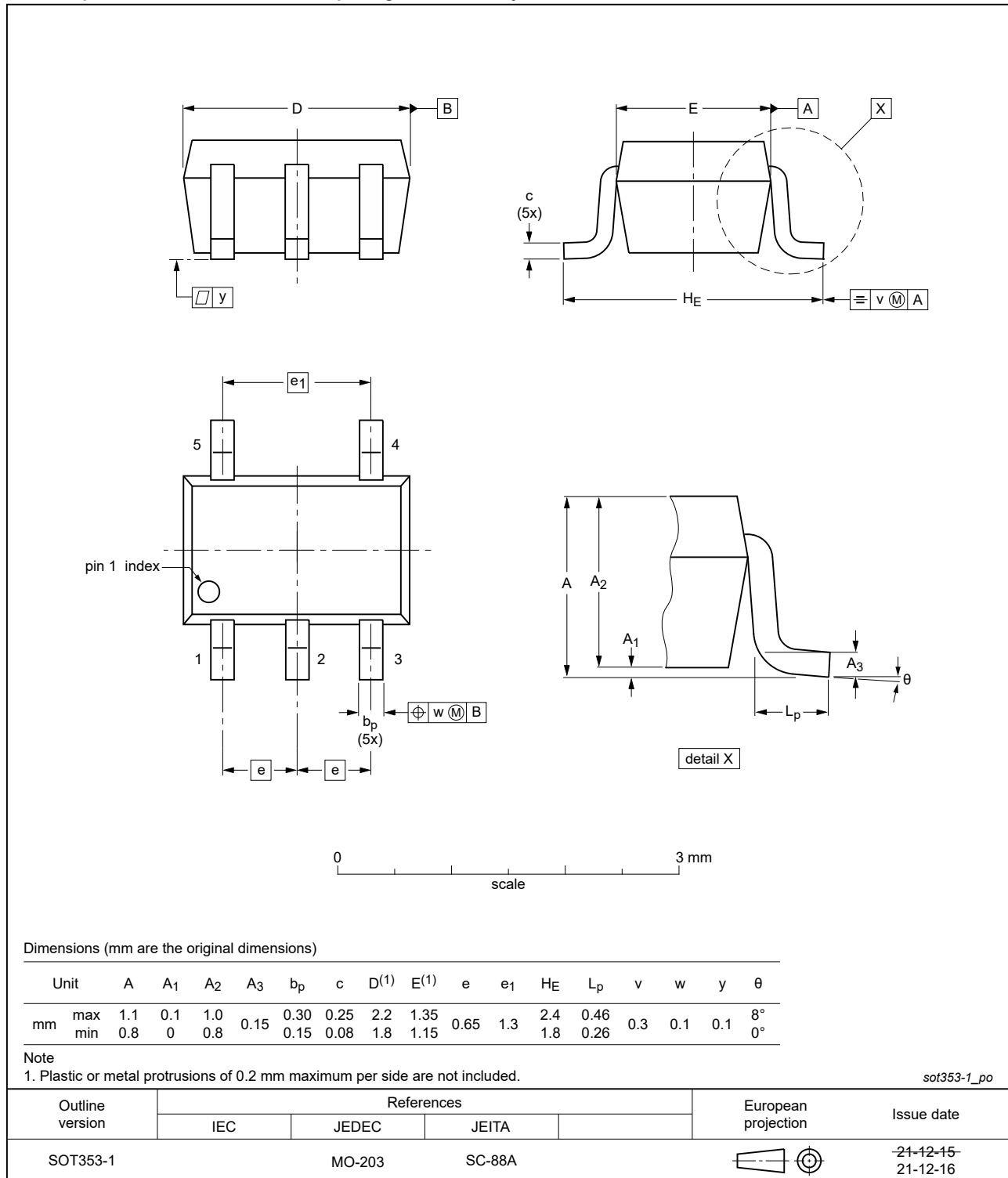


Fig. 11. Package outline SOT353-1 (TSSOP5)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

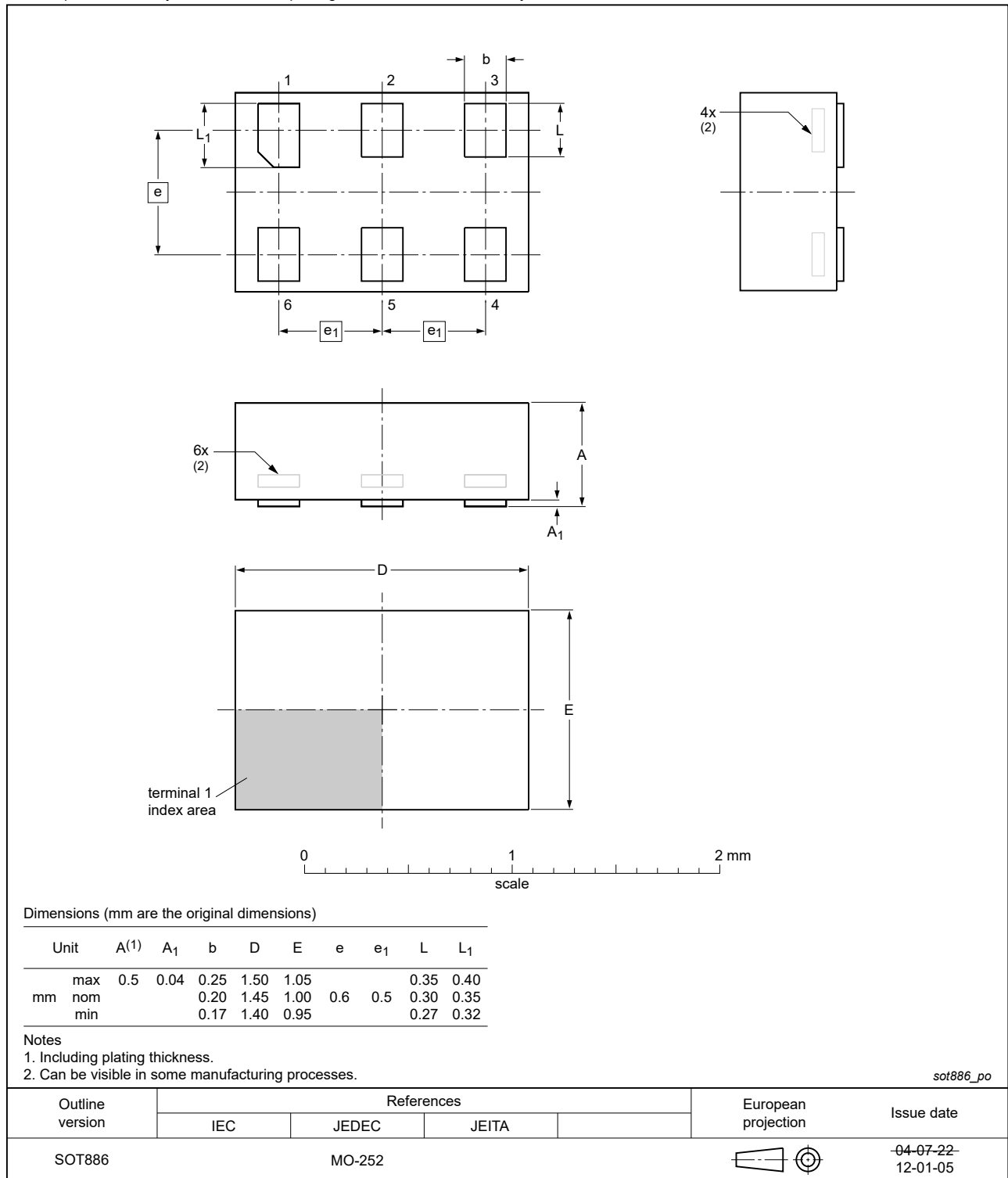
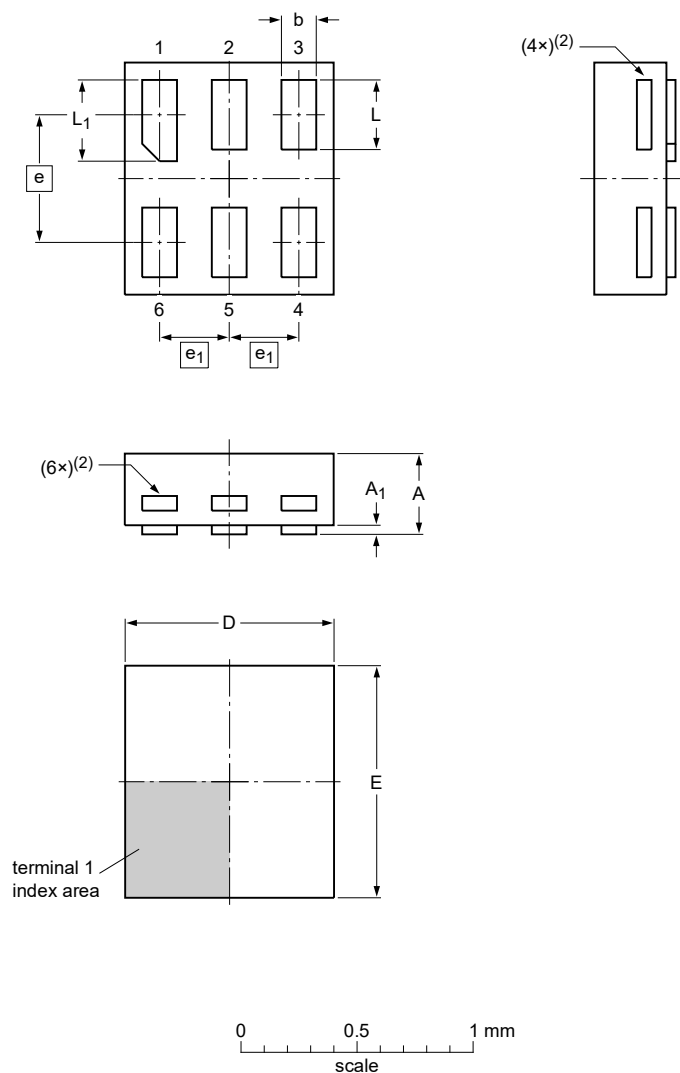


Fig. 12. Package outline SOT886 (XSON6)

**XSON6: extremely thin small outline package; no leads;
6 terminals; body 0.9 x 1.0 x 0.35 mm**

SOT1115



Dimensions

Unit	A ⁽¹⁾	A ₁	b	D	E	e	e ₁	L	L ₁
mm	max 0.35	0.04	0.20	0.95	1.05			0.35	0.40
	nom		0.15	0.90	1.00	0.55	0.3	0.30	0.35
	min		0.12	0.85	0.95			0.27	0.32

Note

- Including plating thickness.
- Visible depending upon used manufacturing technology.

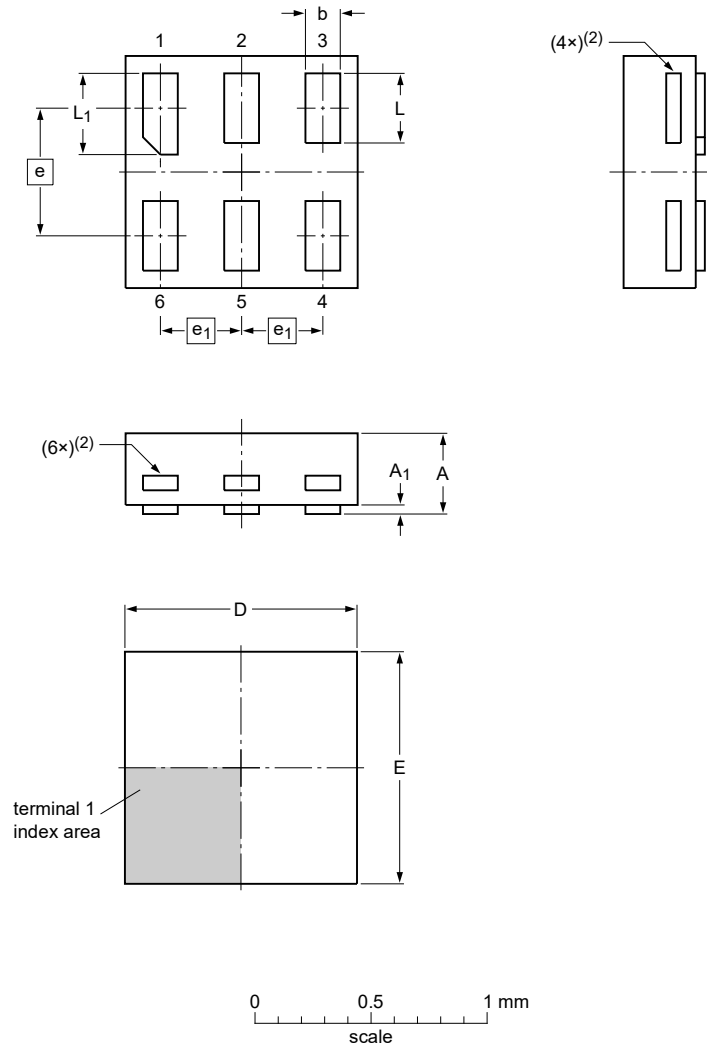
sot1115_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1115						10-04-02 10-04-07

Fig. 13. Package outline SOT1115 (XSON6)

**XSON6: extremely thin small outline package; no leads;
6 terminals; body 1.0 x 1.0 x 0.35 mm**

SOT1202



Dimensions

Unit	A ⁽¹⁾	A ₁	b	D	E	e	e ₁	L	L ₁
mm	max	0.35	0.04	0.20	1.05	1.05		0.35	0.40
	nom			0.15	1.00	1.00	0.55	0.30	0.35
	min			0.12	0.95	0.95		0.27	0.32

Note

- Including plating thickness.
- Visible depending upon used manufacturing technology.

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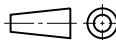
Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT1202						10-04-02 10-04-06

Fig. 14. Package outline SOT1202 (XSON6)

X2SON5: plastic thermal enhanced extremely thin small outline package; no leads;
5 terminals; body 0.8 x 0.8 x 0.32 mm

SOT1226-3

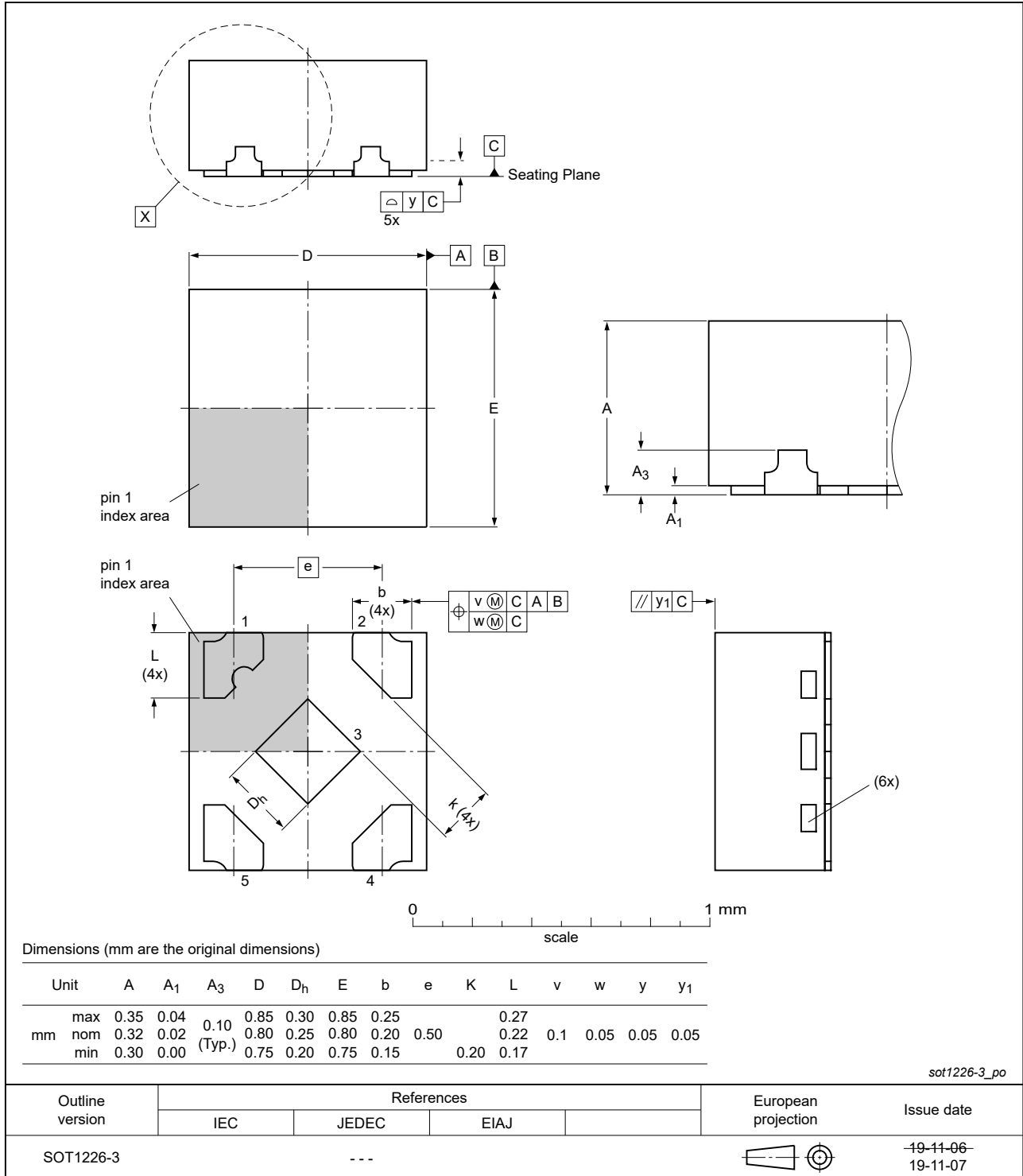


Fig. 15. Package outline SOT1226-3 (X2SON5)

XSON5: Plastic thermal enhanced extremely thin small outline package with side-wettable flanks (SWF); no leads; 5 terminals; body 1.1 × 0.85 × 0.5 mm

SOT8065-1

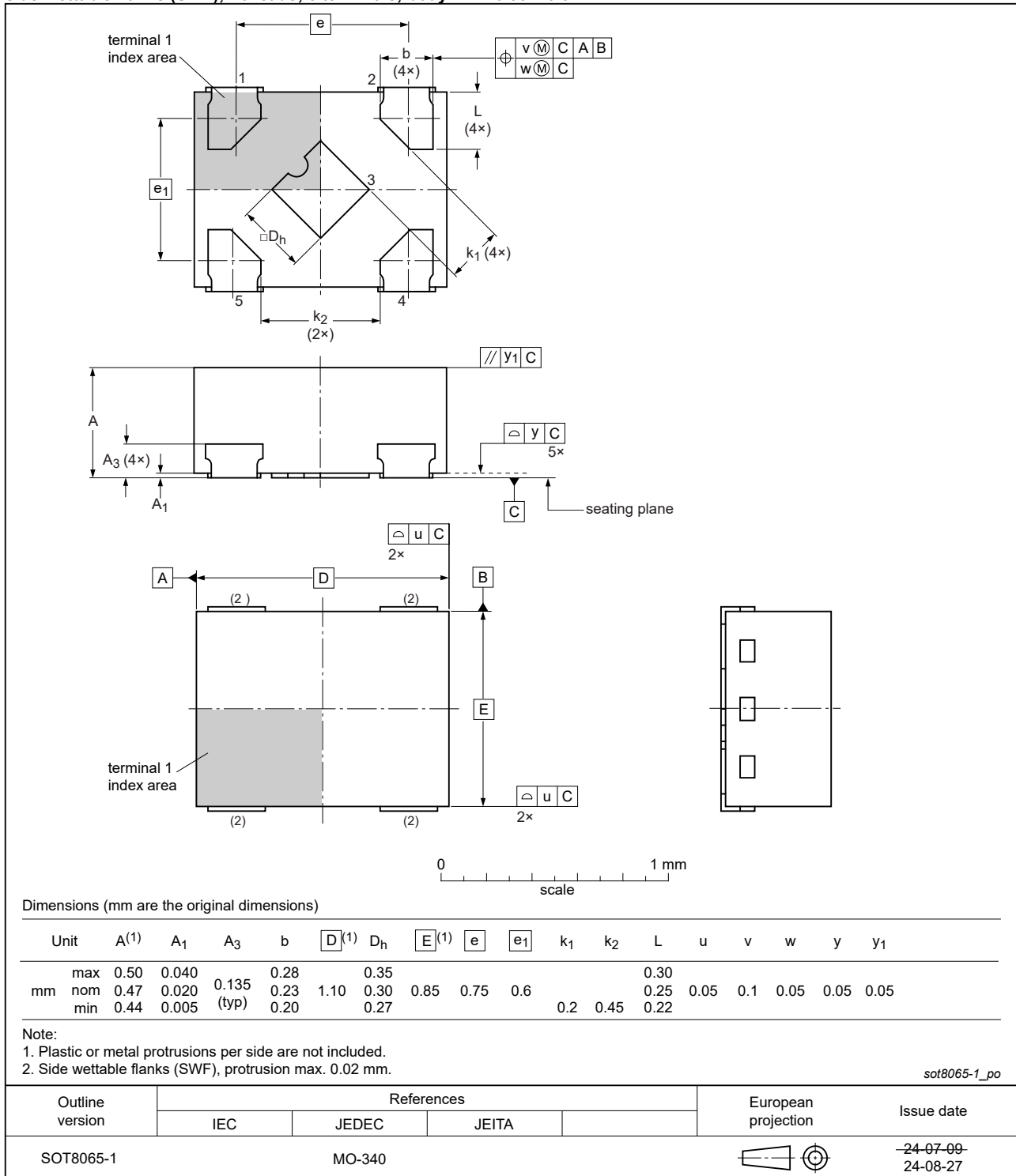


Fig. 16. Package outline SOT8065-1 (XSON5)

15. Abbreviations

Table 12. Abbreviations

Acronym	Description
ANSI	American National Standards Institute
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
ESDA	ElectroStatic Discharge Association
HBM	Human Body Model
JEDEC	Joint Electron Device Engineering Council

16. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G132 v.10	20240923	Product data sheet	-	74AUP1G132 v.9.1
Modifications:	<ul style="list-style-type: none"> Type number 74AUP1G132GZ (SOT8065-1/XSON5) added. 			
74AUP1G132 v.9.1	20230711	Product data sheet	-	74AUP1G132 v.8
Modifications:	<ul style="list-style-type: none"> Section 2: ESD specification updated according to the latest JEDEC standard. 			
74AUP1G132 v.8	20220114	Product data sheet	-	74AUP1G132 v.7
Modifications:	<ul style="list-style-type: none"> Fig. 11: Package outline drawing for SOT353-1 (TSSOP5) has changed. 			
74AUP1G132 v.7	20210709	Product data sheet	-	74AUP1G132 v.6
Modifications:	<ul style="list-style-type: none"> SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package. Type number 74AUP1G132GF (SOT891) removed. Section 1 and Section 2 updated. Table 5: Derating values for P_{tot} total power dissipation updated. 			
74AUP1G132 v.6	20190501	Product data sheet	-	74AUP1G132 v.5
Modifications:	<ul style="list-style-type: none"> The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Pin configuration drawing SOT1226 (X2SON5) updated. 			
74AUP1G132 v.5	20120629	Product data sheet	-	74AUP1G132 v.4
Modifications:	<ul style="list-style-type: none"> Added type number 74AUP1G132GX (SOT1226) Package outline drawing of SOT886 (Fig. 12) modified. 			
74AUP1G132 v.4	20111124	Product data sheet	-	74AUP1G132 v.3
Modifications:	<ul style="list-style-type: none"> Legal pages updated. 			
74AUP1G132 v.3	20101029	Product data sheet	-	74AUP1G132 v.2
74AUP1G132 v.2	20090615	Product data sheet	-	74AUP1G132 v.1
74AUP1G132 v.1	20061020	Product data sheet	-	-

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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